

500mA 8kV HIGH VOLTAGE DIODES

Finds use in applications such as Monitors,
Static electricity dust collectors,Laser power
supplies,ect..

Features

- High speed switching
- High Current
- High surge resisitivity for CRT discharge
- High reliability design
- High Voltage

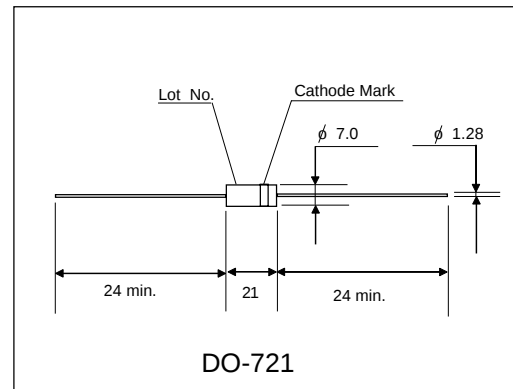
Applications

- X light Power supply
- Laser
- Voltage doubler circuit
- Microwave emission power

Maximum Ratings and Characteristics

- Absolute Maximum Ratings

Outline Drawings : mm



Cathode Mark

Type	Mark
ESJC50F08	

Items	Symbols	Condition	ESJC50F08	Units
Repetitive Peak Renerse Voltage	V_{RRM}		8.0	kV
Average Output Current	I_o	$T_a=25^{\circ}C$,Resistive Load	500	mA
Suege Current	I_{FSM}		30	A _{peak}
Junction Temperature	T_J		120	$^{\circ}C$
Allowable Operation Case Temperature	T_c		120	$^{\circ}C$
Storage Temperature	T_{stg}		-40 to +125	$^{\circ}C$

- Electrical Characteristics ($T_a=25^{\circ}C$ Unless otherwise specified)

Items	Symbols	Conditions	ESJC50F08	Units
Maximum Forward Voltage Drop	V_F	at $25^{\circ}C$, $I_F = I_{F(AV)}$	14	V
Maximum Reverse Current	I_{R1}	at $25^{\circ}C$, $V_R = V_{RRM}$	5.0	μA
	I_{R2}	at $100^{\circ}C$, $V_R = V_{RRM}$	50	μA
Maximum Reverse Recovery Time	T_{rr}	at $25^{\circ}C$	100	nS
Junction Capacitance	C_j	at $25^{\circ}C$, $V_R=0V$, $f=1MHz$	--	pF